

General Description

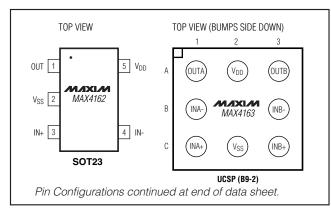
The MAX4162/MAX4163/MAX4164 are single/dual/quad, micropower operational amplifiers that combine an exceptional bandwidth to power consumption ratio with true rail-to-rail inputs and outputs. They consume a mere 25µA quiescent current per amplifier, vet achieve 200kHz gain-bandwidth product and are unity-gain stable while driving any capacitive load. The MAX4162/ MAX4163/MAX4164 operate from either a single supply (2.5V to 10V) or dual supplies (±1.25V to ±5V), with an input common-mode voltage range that extends 250mV beyond either supply rail. These amplifiers use a proprietary architecture to achieve a very high input commonmode rejection ratio without the midswing nonlinearities present in other rail-to-rail op amps. This architecture also maintains high open-loop gain and output swing while driving substantial loads.

The combination of excellent bandwidth/power performance, single-supply operation, and miniature footprint makes these op amps ideal for portable equipment and other low-power, single-supply applications. The single MAX4162 is available in 8-pin SO and space-saving 5-pin SOT23 packages. The MAX4163 is available in an 8-pin ultra chip-scale package (UCSPTM) and an 8-pin μ MAX® or SO package. The MAX4164 is available in a 14-pin SO package.

Applications

Battery-Powered Devices pH Probes Portable Equipment Low-Power, Low-Voltage Equipment Medical Instruments Ionization Detectors Cellular Phones

Pin Configurations



UCSP is a trademark and μ MAX is a registered trademark of Maxim Integrated Products, Inc.

Features

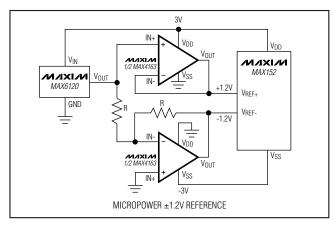
- ♦ UCSP Package (MAX4163)
- ◆ 1.0pA Typical Input Bias Current
- ♦ Single-Supply Operation from 2.5V to 10V
- ♦ Input Common-Mode Voltage Range Extends 250mV Beyond Either Supply Rail
- ♦ Rail-to-Rail Output Swing
- ♦ 200kHz Gain-Bandwidth Product
- ♦ 25µA Quiescent Current per Amplifier
- **♦ Excellent CMRR, PSRR, and Gain Linearity**
- ♦ No Phase Reversal for Overdriven Inputs
- ♦ Unity-Gain Stable
- ♦ Stable with Any Capacitive Load
- ♦ Internally Short-Circuit Protected to Either Rail

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4162ESA	-40°C to +85°C	8 SO	_
MAX4162EUK-T	-40°C to +85°C	5 SOT23	AABX
MAX4163EBL-T*	-40°C to +85°C	8 UCSP	AAX
MAX4163ESA	-40°C to +85°C	8 SO	_
MAX4163EUA	-40°C to +85°C	8 µMAX	_
MAX4164ESD	-40°C to +85°C	14 SO	_

*UCSP reliability is integrally linked to the user's assembly methods, circuit board material, and environment. Refer to the UCSP Reliability Notice in the UCSP Reliability section of this data sheet for more information.

Typical Application Circuit



MIXIM

Maxim Integrated Products

ABSOLUTE MAXIMUM RATINGS

Supply Voltage (V _{DD} to V _{SS})	11V
IN+, IN-, OUT Voltage(V _{DD} + 0.3V) to (V _{SS}	s - 0.3V)
Short-Circuit Duration (to either rail)Cor	ntinuous
Continuous Power Dissipation ($T_A = +70$ °C)	
5-Pin SOT23 (derate 7.1mW/°C above +70°C)	.571mW
8-Pin SO (derate 5.88mW/°C above +70°C)	.471mW
8-Pin UCSP (derate 4.7mW/°C above +70°C)	.379mW

8-Pin µMAX (derate 4.1mW/°C above +70°	C)330mW
14-Pin SO (derate 8.00mW/°C above +70°C	C)640mW
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS: 3V Operation

. $(V_{DD}=3V,\,V_{SS}=0,\,V_{CM}=V_{DD}/2,\,V_{OUT}=V_{DD}/2,\,R_L$ tied to $V_{DD}/2,\,T_A=-40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_A=+25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL		CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage Range	V _{DD}	Inferred from	PSRR test	2.5		10.0	V
Supply Current (Per Amplifier)	I _{DD}				25	40	μΑ
Input Bias Current (Note 2)	IB				1.0	100	рА
		MAX4162	T _A = +25°C		±0.5	±3	
		WAX4102	$T_A = -40$ °C to $+85$ °C			±4	1
Input Offset Voltage	Vos	MAX4163	T _A = +25°C		±0.5	±4	mV
	VOS	IVIAA4 103	$T_A = -40$ °C to $+85$ °C			±5	IIIV
		MAX4164	T _A = +25°C		±0.5	±5	
		IVIAA4 104	$T_A = -40$ °C to $+85$ °C			±6	
Input Offset Voltage Tempco	TCVos				2		μV/°C
Differential Input Resistance	RiN				>10		TΩ
Input Common-Mode Voltage Range	V _{CM}	Inferred from	CMRR test	V _{SS} - 0.25		V _{DD} + 0.25	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = (V_{SS} - 0.25V)$ to $(V_{DD} + 0.25V)$		70	100		dB
Large-Signal Voltage Gain	Ay	$R_L = 10k\Omega$	$R_L = 10k\Omega$		120		dB
	V _{OUT}	$R_L = 10k\Omega$	V _{DD} - V _{OH}		30	180	- mV
Output Voltage Swing		HE TOKS2	V _{OL} - V _{SS}		30	180	
Output voltage Swing		$R_L = 100 k\Omega$	V _{DD} - V _{OH}		3	25	
			V _{OL} - V _{SS}		3	25	
Output Short-Circuit Current	Isc	To either sup	pply rail		15		mA
Closed-Loop Output Resistance	Rout	$A_V = 1V/V$			0.1		Ω
Power-Supply Rejection Ratio	PSRR	$V_{DD} = 2.5V t$	o 10V	80	110		dB
Gain-Bandwidth Product	GBWP				200		kHz
Phase Margin	φМ				60		degrees
Gain Margin	GM				12		dB
Total Harmonic Distortion	THD	$f = 1kHz$, $V_{OUT} = 2V_{P-P}$, $R_L = 100k\Omega$, $A_V = 1V/V$			0.02		%
Slew Rate	SR				115		V/ms
Settling Time to 0.1%		V _{OUT} = 1V to 2V step			50		μs
Turn-On Time	ton	$V_{DD} = 0 \text{ to } 3$	$V \text{ step}, V_{IN} = V_{DD}/2, A_V = 1V/V$		20		μs

_ /N/IXI/N

ELECTRICAL CHARACTERISTICS: 3V Operation (continued)

 $(V_{DD}=3V,\,V_{SS}=0,\,V_{CM}=V_{DD}/2,\,V_{OUT}=V_{DD}/2,\,R_L$ tied to $V_{DD}/2,\,T_A=-40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_A=+25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage-Noise Density	en	f = 1kHz		80		nV/√Hz
Differential Input Capacitance				0.7		pF
Input Common-Mode Capacitance				1.5		pF
Internal Charge-Pump Frequency				700		kHz
Charge-Pump Output Feedthrough				100		μV _{P-P}

ELECTRICAL CHARACTERISTICS: 5V Operation

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C}$.) (Note 1)

PARAMETER	SYMBOL		CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage Range	V _{DD}	Inferred from	PSRR test	2.5		10.0	V
Supply Current (Per Amplifier)	I _{DD}				25	45	μΑ
Input Bias Current (Note 2)	IB				1.0	100	рА
		MAX4162	TA = +25°C		±0.5	±3	
		IVIAA4 102	$T_A = -40$ °C to $+85$ °C			±4]
Input Offact Valtage	Voc	MAX4163	T _A = +25°C		±0.5	±4	mV
Input Offset Voltage	Vos	IVIAA4163	$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±5	1111
		MAX4164	T _A = +25°C		±0.5	±5	
		IVIAA4 104	$T_A = -40$ °C to $+85$ °C			±6	
Input Offset Voltage Tempco					2		μV/°C
Differential Input Resistance					>10		ΤΩ
Input Common-Mode Voltage Range	V _{CM}	Inferred from	Inferred from CMRR test			V _{DD} + 0.25	V
Common-Mode Rejection Ratio	CMRR	V _{CM} = (V _{SS} -	0.25V) to (V _{DD} + 0.25V)	70	100		dB
Large-Signal Voltage Gain	Av	$R_L = 10k\Omega$		85	120		dB
		D: 10k0	V _{DD} - V _{OH}		50	300	
Outrout Valtage Cuing	\/	$R_L = 10k\Omega$	V _{OL} - V _{SS}		50	300	\/
Output Voltage Swing	Vout	D: 100k0	V _{DD} - V _{OH}		5	40	mV
		$R_L = 100k\Omega$	V _{OL} - V _{SS}		5	40	1
Output Short-Circuit Current	Isc	To either sup	pply rail		15		mA
Closed-Loop Output Resistance	Rout	$A_V = 1V/V$			0.1		Ω
Power-Supply Rejection Ratio	PSRR	V _{DD} = 2.5V to 10V		80	110		dB
Gain-Bandwidth Product	GBWP				200		kHz
Phase Margin	φМ				60		degrees
Gain Margin	GM				12		dB

ELECTRICAL CHARACTERISTICS: 5V Operation (continued)

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, V_{OUT} = V_{DD}/2, R_L \text{ tied to } V_{DD}/2, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C}$.) (Note 1)

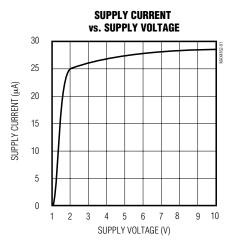
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Total Harmonic Distortion	THD	$f = 1kHz$, $V_{OUT} = 2V_{P-P}$, $R_L = 100k\Omega$, $A_V = 1V/V$		0.02		%
Slew Rate	SR			115		V/ms
Settling Time to 0.1%		V _{OUT} = 1V to 2V step		70		μs
Turn-On Time	ton	$V_{DD} = 0$ to 3V step, $V_{IN} = V_{DD}/2$, $A_V = 1V/V$		40		μs
Input Voltage-Noise Density	en	f = 1kHz		80		nV/√Hz
Differential Input Capacitance				0.7		pF
Input Common-Mode Capacitance				1.5		pF
Internal Charge-Pump Frequency				700		kHz
Charge-Pump Output Feedthrough				100		µV _{P-P}

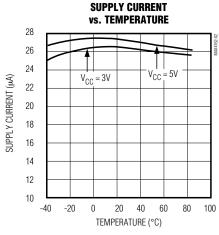
Note 1: All device specifications are 100% tested at T_A = +25°C. Limits over the extended temperature range are guaranteed by design, not production tested.

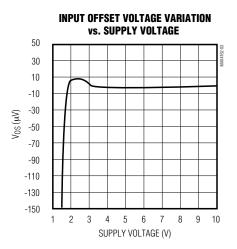
Note 2: Input bias current guaranteed by design, not production tested.

_Typical Operating Characteristics

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_A = +25$ °C, unless otherwise noted.)



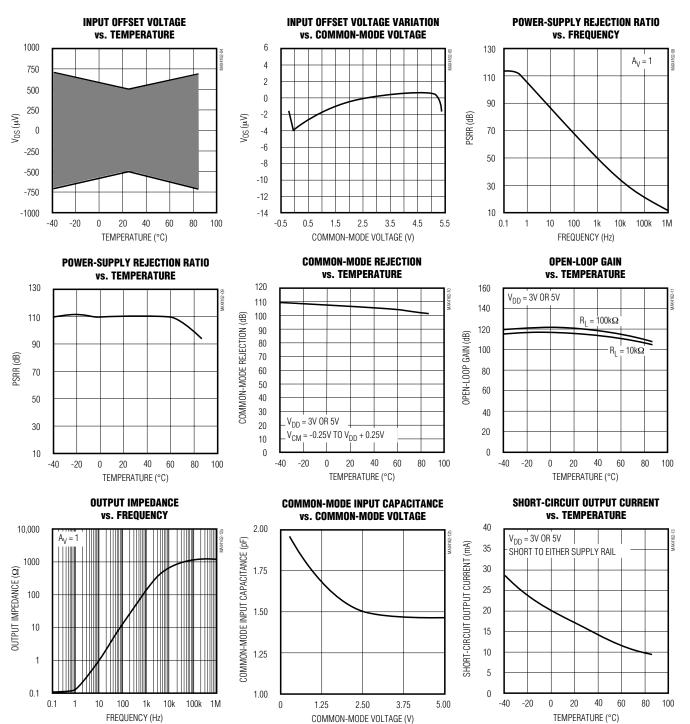




4 ______*N*|*X*|*X*|*X*|

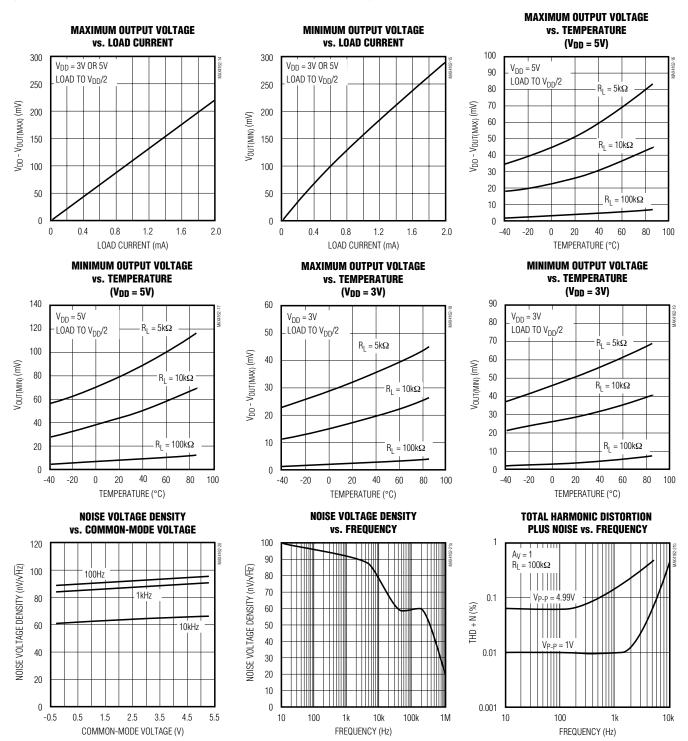
Typical Operating Characteristics (continued)

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_A = +25^{\circ}C$, unless otherwise noted.)



Typical Operating Characteristics (continued)

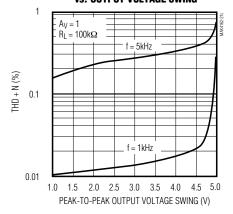
 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_A = +25^{\circ}C, unless otherwise noted.)$



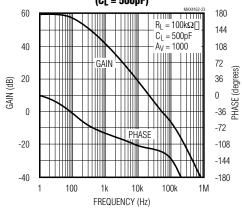
Typical Operating Characteristics (continued)

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_A = +25$ °C, unless otherwise noted.)

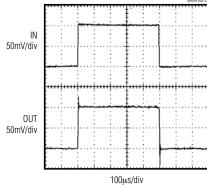
TOTAL HARMONIC DISTORTION PLUS NOISE vs. OUTPUT VOLTAGE SWING



GAIN AND PHASE vs. FREQUENCY $(C_L = 500pF)$

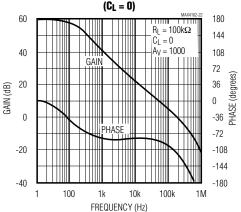


$\begin{array}{c} \text{NONINVERTING} \\ \text{SMALL-SIGNAL PULSE RESPONSE} \\ (\text{V}_{DD} = 3\text{V}, \text{ C}_{L} = 0) \end{array}$

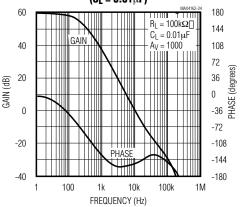


 $V_{DD} = 3V$, $V_{IN} = 100$ mV, $R_L = 100$ k Ω to $V_{DD}/2$, $C_L = 0$

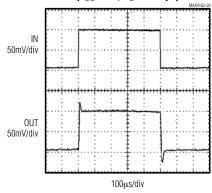
GAIN AND PHASE vs. FREQUENCY



GAIN AND PHASE vs. FREQUENCY ($C_L = 0.01 \mu F$)



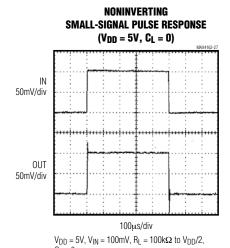
NONINVERTING SMALL-SIGNAL PULSE RESPONSE (VDD = 3V, CL = 1500pF)

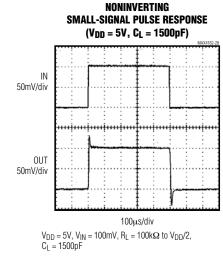


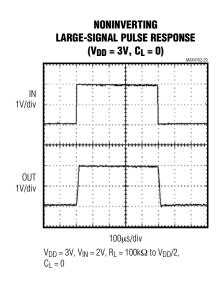
 $V_{DD}=3V,\,V_{IN}=100mV,\,R_L=100k\Omega$ to $V_{DD}/2,\,$ $C_L=1500pF$

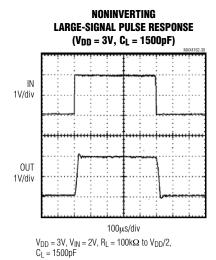
Typical Operating Characteristics (continued)

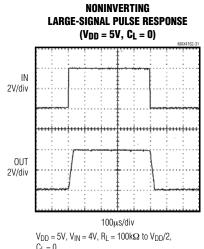
 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_{A} = +25^{\circ}C, \text{ unless otherwise noted.})$





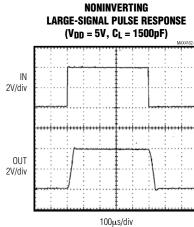


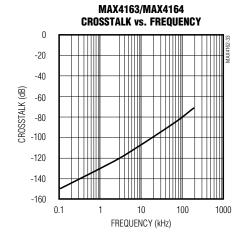




Typical Operating Characteristics (continued)

 $(V_{DD} = 5V, V_{SS} = 0, V_{CM} = V_{DD}/2, T_A = +25$ °C, unless otherwise noted.)





$$\begin{split} V_{DD} = 5 \text{V, } V_{IN} = 4 \text{V, } R_L = 100 \text{k}\Omega \text{ to } V_{DD}/2, \\ C_L = 1500 \text{pF} \end{split}$$

Pin Description

		PIN				
MAX	4162	MAX	4163	MAX4164	NAME	FUNCTION
so	SOT23	SO/µMAX	UCSP	so		
1, 5, 8	_	_	_	_	N.C.	No Connection. Not internally connected.
2	4	_	_	_	IN-	Amplifier Inverting Input
3	3	_	_	_	IN+	Amplifier Noninverting Input
4	2	4	C2	11	V _{SS}	Negative Power Supply
6	1	_	_	_	OUT	Amplifier Output
7	5	8	A2	4	V _{DD}	Positive Power Supply
_	_	1	A1	1	OUTA	Amplifier A Output
_	_	2	B1	2	INA-	Amplifier A Inverting Input
_	_	3	C1	3	INA+	Amplifier A Noninverting Input
_	_	5	C3	5	INB+	Amplifier B Noninverting Input
_	_	6	ВЗ	6	INB-	Amplifier B Inverting Input
_	_	7	АЗ	7	OUTB	Amplifier B Output
_	_	_	_	8	OUTC	Amplifier C Output
_	_	_	_	9	INC-	Amplifier C Inverting Input
_	_	_	_	10	INC+	Amplifier C Noninverting Input
_	_	_	_	12	IND+	Amplifier D Noninverting Input
_	_	_	_	13	IND-	Amplifier D Inverting Input
_	_	_	_	14	OUTD	Amplifier D Output

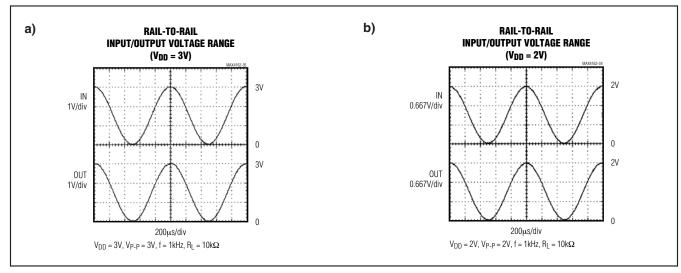


Figure 1. Rail-to-Rail I/O: a) VDD = 3V; b) VDD = 2V

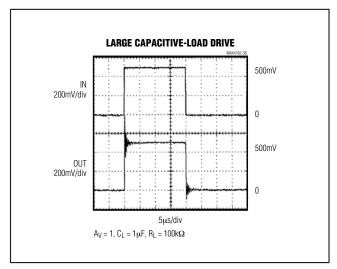


Figure 2. Large Capacitive-Load Drive

Applications Information

Rail-to-Rail Inputs and Outputs

The MAX4162/MAX4163/MAX4164 input common-mode range extends 250mV beyond each of the supply rails, providing a substantial increase in dynamic range over other op amps (even many of those referred to as rail-to-rail). Although the minimum operating voltage is specified at 2.5V, the devices typically provide full rail-to-rail operation below 2.0V (Figure 1). These amplifiers do not

suffer from midswing common-mode-rejection degradation or crossover nonlinearity often encountered in other rail-to-rail op amps. Extremely low, 1.0pA input bias current makes these devices ideal for applications such as pH probes, electrometers, and ionization detectors. They are also protected against phase reversal (inferred from CMRR test) and latchup for input signals extending beyond the supply rails. The output stage achieves a lower output impedance than traditional rail-to-rail output stages, providing an output voltage range that typically swings within 150mV of the supply rails for 1mA loads. This architecture also maintains high open-loop gain and output swing while driving substantial loads.

Output Loading and Stability

These devices drive 1mA loads to within 150mV of the supply rails while consuming only 25µA of quiescent current. Internal compensation allows these amplifiers to remain unity-gain stable while driving any capacitive load (Figure 2).

Internal Charge Pump

An internal charge pump provides two internal supplies typically 2V beyond each rail. These internal rails allow the MAX4162/MAX4163/MAX4164 to achieve true rail-to-rail inputs and outputs, while providing excellent common-mode rejection, power-supply rejection ratios, and gain linearity.

These charge pumps require no external components, and in most applications are entirely transparent to the user. Two characteristics may be visible to the user, depending on the application:

10 ______/N/1X//N

- 1) The on-board charge pumps generate a small amount of 700kHz switching noise at the op amp's output. The amplitude of this noise is typically 100μVP-P. The noise is **not** referred to the input, and is independent of amplifier gain. The charge-pump switching frequency is well beyond the amplifier's 200kHz bandwidth, and is therefore unnoticeable in most applications.
- 2) The charge pumps typically require up to 20µs on power-up to fully energize the internal supply rails (Figure 3).

Power Supplies and Layout

The MAX4162/MAX4163/MAX4164 are guaranteed to operate from a single 2.5V to 10.0V power supply, but full rail-to-rail operation typically extends below 2V. For single-supply operation, bypass the power supply with a 1µF capacitor in parallel with a 0.1µF ceramic capacitor. If operating from dual supplies, bypass each supply to ground.

Good layout improves performance by decreasing the amount of stray capacitance at the op amp's inputs and output. To decrease stray capacitance, minimize both trace and external component lead lengths, and place external components close to the op amp's pins.

UCSP Package Consideration

For general UCSP package information and PC layout considerations, please refer to the Maxim Application Note (Wafer-Level Ultra-Chip-Board-Scale-Package).

UCSP Reliability

The UCSP represents a unique packaging form factor that may not perform equally to a packaged product through traditional mechanical reliability tests. UCSP reliability is integrally linked to the user's assembly methods, circuit board material, and usage environment. The user should closely review these areas when considering use of a UCSP. Performance through operating life test and moisture resistance remains uncompromised as it is primarily determined by the wafer-fabrication process. Mechanical stress performance is a greater consideration for a UCSP package. UCSPs are attached through direct solder contact to the user's PC board, foregoing the inherent stress relief of a packaged product lead frame. Solder joint contact integrity must be considered.

Table 1 shows the testing done to characterize the UCSP reliability performance. In conclusion, the UCSP is capable of performing reliably through environmental stresses as indicated by the results in the table. Additional usage data and recommendations are detailed in the UCSP application note, which can be found on Maxim's website at www.maxim-ic.com.

Table 1. Reliability Test Data

TEST	CONDITIONS	DURATION	NO. OF FAILURES PER SAMPLE SIZE
Temperature Cycle	-35°C to +85°C, -40°C to +100°C	150 cycles, 900 cycles	0/10, 0/200
Operating Life	T _A = +70°C	240h	0/10
Moisture Resistance	-20°C to +60°C, 90% RH	240h	0/10
Low-Temperature Storage	-20°C	240h	0/10
Low-Temperature Operational	-10°C	24h	0/10
Solderability	8h steam age	_	0/15
ESD	±2000V, Human Body Model	_	0/5
High-Temperature Operating Life	$T_{J} = +150^{\circ}C$	168h	0/45

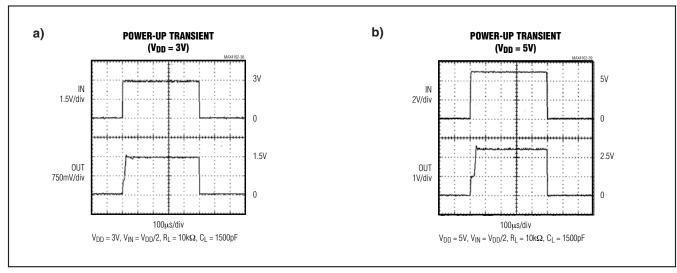
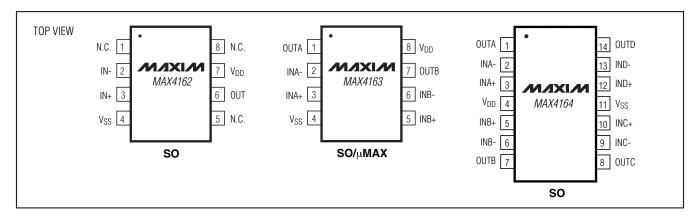


Figure 3. Power-Up Transient: a) $V_{DD} = 3V$; b) $V_{DD} = 5V$

Pin Configurations (continued)



Chip Information

MAX4162 TRANSISTOR COUNT: 291 MAX4163 TRANSISTOR COUNT: 496 MAX4164 TRANSISTOR COUNT: 992

Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
8 SO	S8-2, S8-4	<u>21-0041</u>
5 SOT23	U5-1	21-0057
8 UCSP	B9-5	21-0093
8 µMAX	U8-1	21-0036
14 SO	S14M-5	21-0041

Revision History

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	5/09	Changed operating supply voltage from 2.7V to 2.5V	1, 2, 3, 10, 11

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